

Appl. No. 09/420,887

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No. : 09/420,887
Applicant : Puthiya K. Nizar
Filed : 10/19/1999
TC/A.U. : 2186
Examiner : ROBERTSON, DAVID L.

Confirmation No. 3400

Docket No. : 042390.P7149
Customer No. : 8791

Commissioner for Patents
P.O. Box 1450
Alexandria VA 22313-1450

DECLARATION

Sir:

The article *Intel Offers SDRAM Alternative to Rambus on Camino Chipset* ISSN 0268-716X from Computergram International (Computergram) is describing the work of Puthiya K. Nizar and myself, Khong S. Foo, and described and claimed in the above patent application.

I hereby declare that all statements made herein of my own knowledge are true and that the statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Dated: 10/29/04

By

Khong S. Foo

Docket No: 042390.P7149

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Dated: 10-22-04 By Puthiya K. Nizar
Puthiya K. Nizar

Docket No: 042390.P7149

Page 1 of 1

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